

**SURFACE MOUNT GLASS PASSIVATED
SUPER FAST SILICON RECTIFIER**
VOLTAGE RANGE 50 to 600 Volts CURRENT 2.0 Ampere

FEATURES

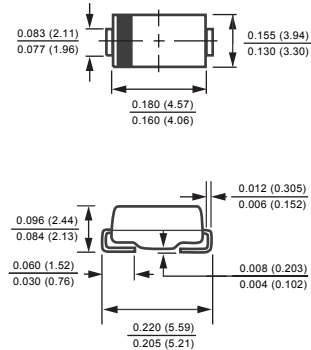
- * Glass passivated device
- * Ideal for surface mounted applications
- * Low leakage current
- * Metallurgically bonded construction
- * Mounting position: Any
- * Weight: 0.098 gram

MECHANICAL DATA

- * Epoxy : Device has UL flammability classification 94V-0



DO-214AA



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

MAXIMUM RATINGS (@ TA=25 °C unless otherwise noted)

RATINGS	SYMBOL	EFM201	EFM202	EFM203	EFM204	EFM205	EFM206	EFM207	UNITS
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	150	200	300	400	600	Volts
Maximum RMS Voltage	V _{RMS}	35	70	105	140	210	280	420	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	150	200	300	400	600	Volts
Maximum Average Forward Rectified Current at T _A = 55°C	I _O	2.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	75							Amps
Typical Thermal Resistance (Note 4)	R _{θJA}	75				75			°C/W
	R _{θJL}	20				25			
Typical Junction Capacitance (Note 2)	C _J	30				20			pF
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to + 150							°C

ELECTRICAL CHARACTERISTICS (@TA=25 °C unless otherwise noted)

CHARACTERISTICS		SYMBOL	EFM201	EFM202	EFM203	EFM204	EFM205	EFM206	EFM207	UNITS
Maximum Instantaneous Forward Voltage at 2.0A DC		V _F	0.95				1.25		1.50	Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage	@T _A = 25°C	I _R	5.0							μAmps
	@T _A = 100°C		100							
Maximum Reverse Recovery Time (Note 1)		t _{rr}	35						50	nSec

NOTES : 1. Reverse Recovery Test Conditions: I_F = 0.5A, I_R = -1.0A, I_{RR} = -0.25A
2. Measured at 1 MHz and applied reverse voltage of 4.0 volts
3. "Fully ROHS compliant", "100% Sn plating (Pb-free)".
4. Thermal Resistance : Mounted on PCB.

2006-11
REV:C

RATING AND CHARACTERISTICS CURVES (EFM201 THRU EFM207)

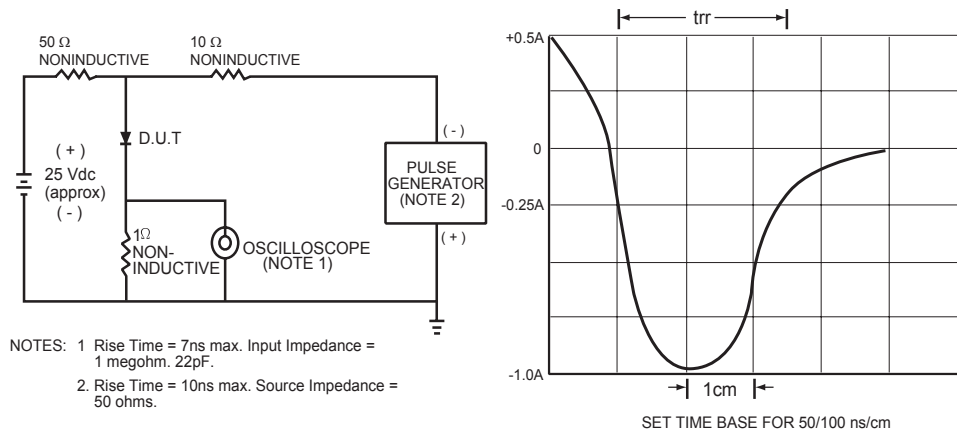


FIG.1 TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

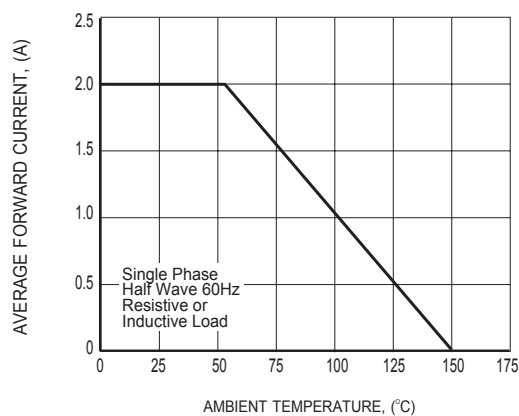


FIG.2 TYPICAL FORWARD CURRENT DERATING CURVE

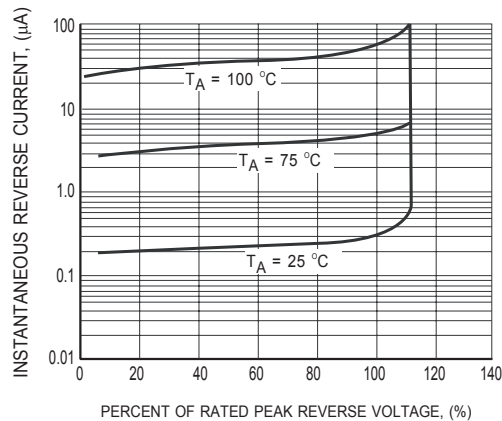


FIG.3 TYPICAL REVERSE CHARACTERISTICS

RATING AND CHARACTERISTICS CURVES (EFM201 THRU EFM207)

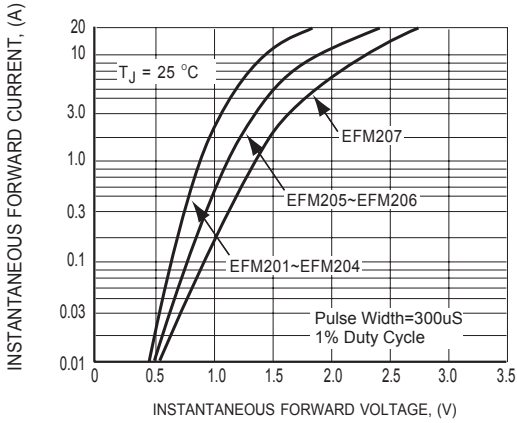


FIG.4 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

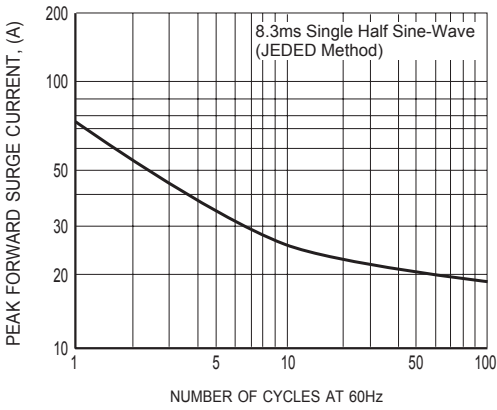


FIG.5 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

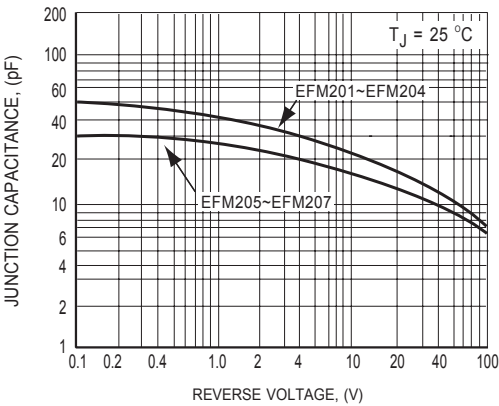
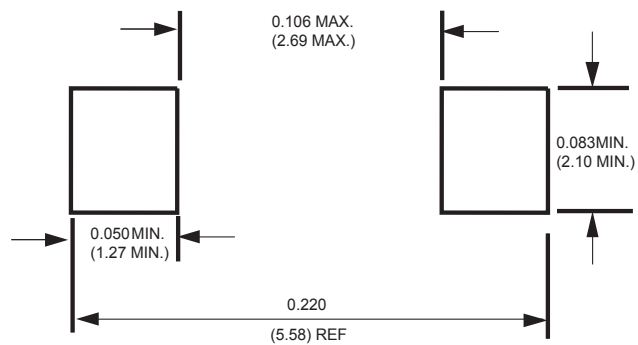


FIG.6 TYPICAL JUNCTION CAPACITANCE

Mounting Pad Layout



Dimensions in inches and (millimeters)

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9